

## PH976DBR 976nm Series

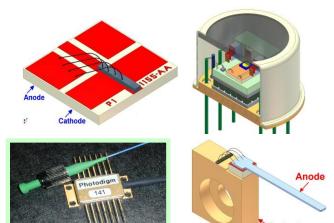
# **High-Power Single-Frequency Laser Diode**

### **Technology**

- DBR Single-Frequency Laser Chip
- InGaAs QW Active Layer
- Epi designed for high reliability

#### **Features**

- Available in several package styles
- Pulsed operation for spectral stability at short pulse lengths
- High power for CW applications
- High Slope Efficiency



#### Description

The PH976DBR Series of high-power edge-emitting lasers are based on Photodigm's advanced single-frequency laser technology. It provides a diffraction limited, single lateral and longitudinal mode beam. Facets are passivated for high-power reliability. Applications include Yb narrow band pumping, spectroscopy, difference frequency generation, and low power DPSS replacement.

### **Absolute Maximum Ratings**

Parameter	Symbol	Unit	Min	Max
Storage Temperature	T <sub>STG</sub>	°C	0	80
Operating Temperature	T <sub>OP</sub>	°C	5.0	70
CW Laser Forward Current, T=T <sub>op</sub>	I <sub>F</sub>	mA	-	250**
Pulsed Laser Forward Current, T=25°C, PW=300 ns, DC=10%	I <sub>F</sub>	Α	-	0.5
Laser Reverse Voltage	$V_R$	V	-	2.0
Photodiode Forward Current 1/2/	I <sub>P</sub>	mA	-	5.0
Photodiode Reverse Voltage 1/2/	$V_R$	V	-	20.0
Photodiode Dark Current, V <sub>R</sub> =10V, LD I <sub>F</sub> =0, <u>2</u> /	I <sub>D</sub>	nA	-	50
TEC Current 1/2/	I <sub>TEC</sub>	Α	-1.8	1.8
TEC Voltage 1/2/	$V_{TEC}$	V	-1.9	1.9
Thermistor Current 1/2/	I <sub>THRM</sub>	mA	-	1.0
Thermistor Voltage 1/2/	$V_{THRM}$	V	-	10
External Back Reflection	-	dB	-	-14
ESD (HBM)	-	V	-	500
Lead Soldering Temperature, 10 sec. Max., 2/	-	°C	-	260
Fiber Pull Force 1/	-	N	-	5.0
Fiber Bend Radius <u>1</u> /	-	mm	-	35

<sup>1/</sup> Butterfly package 2/ TO-8 packag\*\* Do not exceed drive current or operating power of supplied LIV\*\*



CW Characteristics at T<sub>C</sub> = 25°C unless otherwise specified

Parameter	Symbol	Unit	Min	Тур	Max
Center Wavelength	λς	nm	974	976	978
Optical Output Power @ LIV current	Po	mW	See Power Options Call-out		
Slope Efficiency, <u>1</u> /	ηd	W/A	0.3	0.36	
Slope Efficiency	ηd	W/A	0.6	0.72	-
Threshold Current	lth	mΑ	-	30	40
Laser Series Resistance	Rs	Ω	-	2.0	2.5
Laser Forward Voltage	$V_{F}$	V	-	2.0	2.5
Thermistor Resistance @ 25°C, <u>2</u> /	$R_T$	ΚΩ	-	10	-
Photodiode Dark Current, V <sub>R</sub> =10V, LD I <sub>F</sub> =0, <u>2</u> /	$I_{D}$	nA	-	-	50
Laser Line Width	$\Delta v$	MHz	-	1	-
Beam Divergence @ FWHM	θιι Χ θ⊥	0	-	6 X 32	8 X 34
Side Mode Suppression Ratio	SMSR	dB	-30	-	-
Polarization Extinction Ratio, 1/	PER	dB	-16	-19	-
Laser Polarization				TE	
Mode Structure			Fundamental Mode		

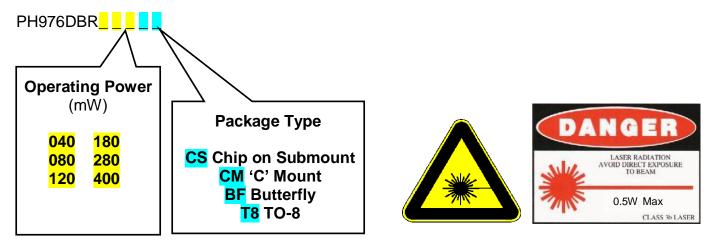
<sup>1/</sup> Butterfly package only 2/ Butterfly and TO-8 package

#### **Handling Precautions**

These devices are sensitive to ESD. When handling the module, grounded work area and wrist strap must be used. Always store in an antistatic container with all leads shorted together.

#### **How To Order**

Part number example: PH976DBR120CM. Assign optical power from those shown below. Use a three-digit format for all power entries. Call factory for special frequency selection and certification to certain atomic absorption lines. Butterfly package is offered at 50% of output power shown.



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